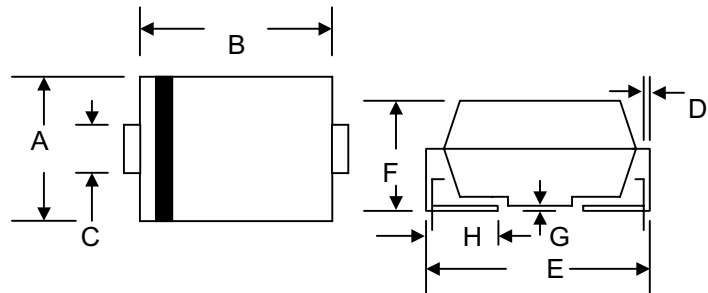


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Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Surge Overload Rating to 30A Peak
- Low Power Loss
- Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O



Mechanical Data

- Case: Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)

SMB/DO-214AA				
Dim	Min	Max	Min	Max
A	3.30	3.94	0.130	0.155
B	4.06	4.70	0.160	0.185
C	1.91	2.11	0.075	0.083
D	0.152	0.305	0.006	0.012
E	5.08	5.59	0.2	0.220
F	2.13	2.44	0.084	0.096
G	0.051	0.203	0.002	0.008
H	0.76	1.27	0.029	0.05
	in mm		In inch	

Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	FR1A	FR1B	FR1D	FR1G	FR1J	FR1K	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	50	100	200	400	600	800	V
Working Peak Reverse Voltage	V_{RWM}							
DC Blocking Voltage	V_R							
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	V
Average Rectified Output Current @ $T_L = 90^\circ\text{C}$	I_o	1.0						A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30						A
Forward Voltage @ $I_F = 1.0A$	V_{FM}	1.30						V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	I_{RM}	5.0 300						μA
Reverse Recovery Time (Note 1)	t_{rr}	150				250	500	nS
Typical Junction Capacitance (Note 2)	C_j	10						pF
Typical Thermal Resistance (Note 3)	$R_{\theta JL}$	30						K/W
Operating and Storage Temperature Range	T_j, T_{STG}	-50 to +150						$^\circ\text{C}$

Note: 1. Measured with $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$,
2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.
3. Mounted on P.C. Board with 8.0mm² land area.

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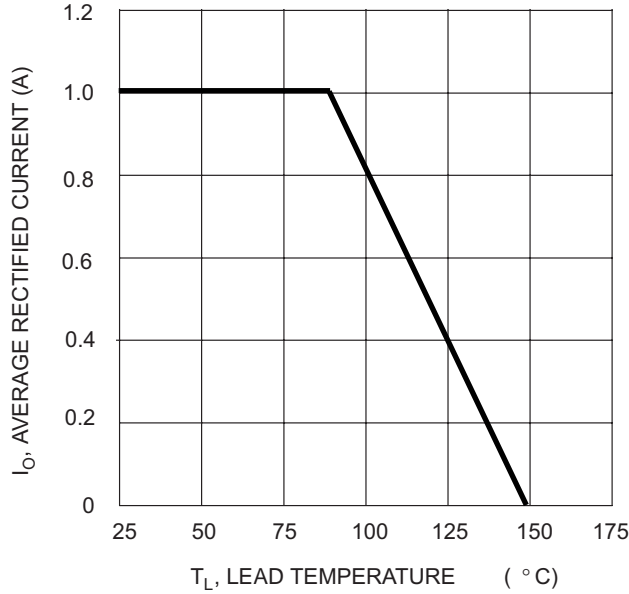


Fig. 1 Forward Current Derating Curve

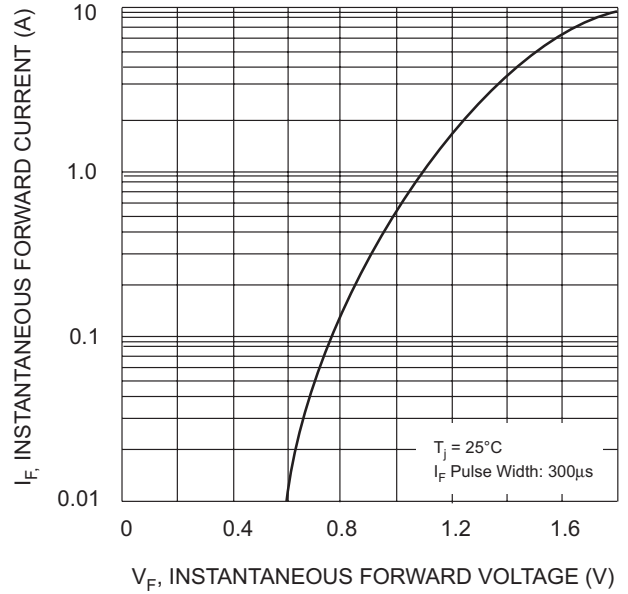


Fig. 2 Typical Forward Characteristics

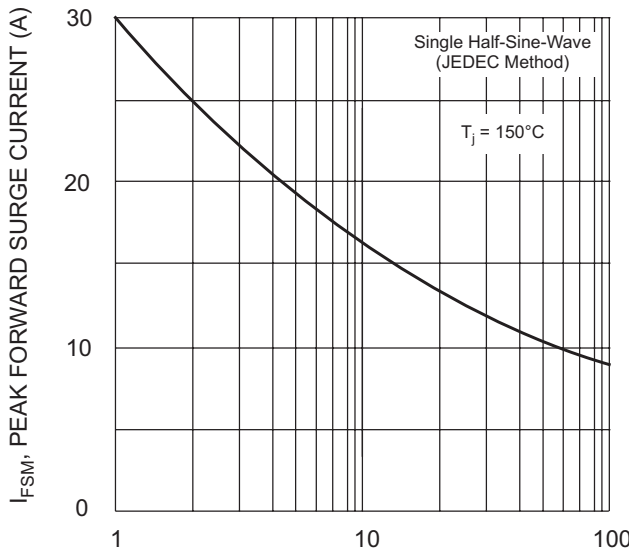


Fig. 3 Forward Surge Current Derating Curve

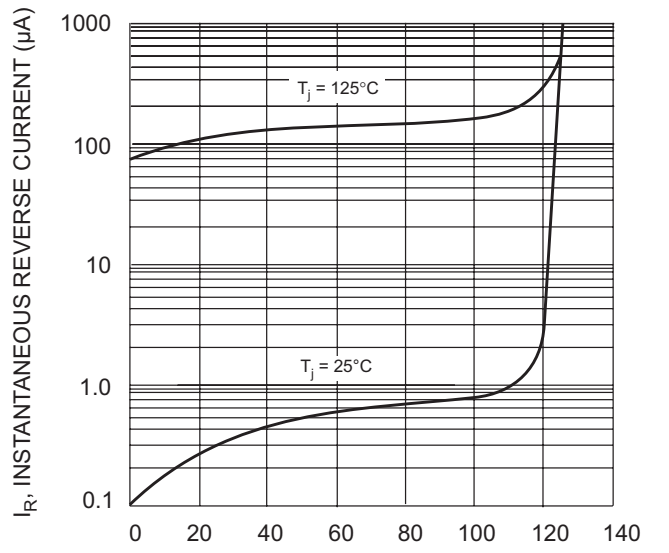
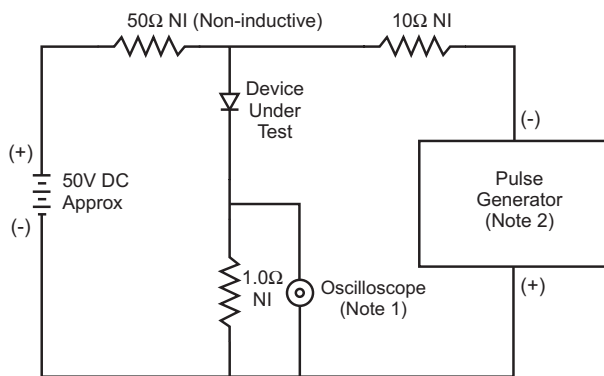
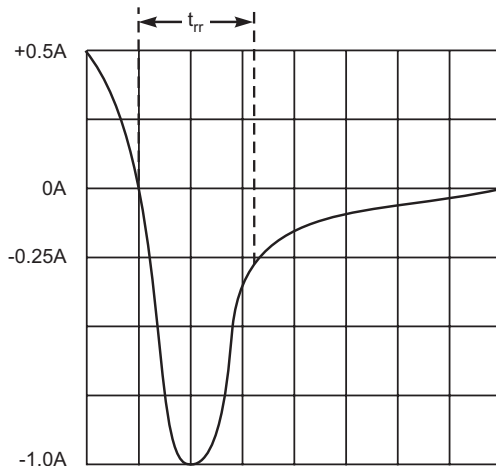


Fig. 4 Typical Reverse Characteristics



- Notes:
 1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

TECHNICAL DATA

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